Derivatives of Trifluoro(trifluoromethyl)silane

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Silicon-Substituted Derivatives of Trifluoro(trifluoromethyl)silane. Some Chemistry of the Silicon–Iodine Bond in a Polyhalo System

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The fluoroiodosilane CF₃SiF₂I has been utilized to generate a series of compounds of formula CF₃SiF₂X, where X = Br, Cl, F, and $OSiF_2CF_3$; all but X = F are new compounds. Conversion of Si-I bonds to Si-X is effected by antimony(III) halides or, for oxygen, mercury(II) oxide. Each of the halodifluoro(trifluoromethyl)silanes undergoes pyrolytic decomposition at 100° to generate SiF₃X and CF₂, although the thermal decomposition of CF₃SiF₂I is quite complex. Each of the CF₃SiF₂X species (other than CF_3SiF_3) reacts with water vapor to generate CF_3SiF_3 and, for X = Br or I, CF_2HX . The halodifluoromethanes evidently result from the reaction of CF2 with HX—the CF2 in turn resulting from the interaction of water vapor and CF3SiF3 at room temperature. Correlations of fluorine chemical shifts and directly bonded silicon-fluorine coupling constants between CF₃SiF₂X species and the corresponding SiF₃X species are presented.

Introduction

The known chemistry of the silicon-iodine bond in polyhalo systems is quite limited. Trichloroiodosilane has been described, but its known reaction chemistry consists of a single reaction.¹ Trifluoroiodosilane remains a rather elusive molecule; several synthetic routes to SiF₃I have been described,²⁻⁴ but no definitive evidence for isolation of the pure compound exists, and its chemical properties remain unknown, except for a purported susceptibility toward redistribution at 700°.2 The absence of a well-characterized reaction chemistry for SiF₃I is particularly unfortunate in view of the extensive use of CF₃I both in generating trifluoromethyl derivatives of main group elements and as a convenient homolytic source of the trifluoromethyl radical.5

An attractive feature of the silicon-iodine bond apparent in the chemistry of iodosilane and iodotrimethylsilane is its ability to serve as the basis for a "conversion series" whereby iodine can be selectively exchanged for a variety of halo or pseudohalo functions via silver⁶ or mercury(II)⁷ halides or pseudohalides. The extension of such a series to Si-I bonds in polyhalo systems has not yet been established, nor has a wide range of halogenating agents been explored.

The synthesis of difluoroiodo(trifluoromethyl)silane, CF₃SiF₂I.⁸ has provided a polyhalosilane (or perhalo if the CF3 group is accorded a pseudohalogen status) containing a Si-I bond whose accessibility and stability permit the systematic development of its reaction chemistry. This compound has recently been utilized in the first synthesis of CF₃SiF₃,^{9,10} the simplest perfluoro(alkylsilane). The chemical and physical properties of several new derivatives of CF3SiF3-of general formula CF₃SiF₂X—will be discussed in the following sections.

Experimental Section

All volatile materials were manipulated in a grease-free vacuum system constructed of borosilicate glass, fluorocarbon polymer stopcocks, and glass "O" ring connectors. Solids were handled in an inert-atmosphere glove box. Reagents were obtained from commercial sources and, subsequent to purity verification, were used as received. Molecular weights were calculated from vapor density measurements (Dumas method). Infrared spectra were taken on a commercial double-grating instrument (Beckman IR-20A) in the range 4000-350 cm⁻¹. ¹⁹F NMR spectra were run on a Varian T-60 (56.4 MHz).

Synthesis of CF₃SiF₂I. Difluoroiodo(trifluoromethyl)silane was synthesized from the low-temperature reaction of silicon difluoride AIC404618

with trifluoroiodomethane, as previously described.⁸ Although the reaction of SiF2 with CF3I has been shown to be quite complex, use of a moderate excess of CF₃I in the reaction mixture allows recovery of the desired product in up to 40% overall yield, based on estimated SiF₂ production.

Reactions of CF3SiF2I with SbX3. "Conversion" reactions were conducted by distilling the CF₃SiF₂I into a bulb containing an excess of the antimony halide and, for X = Cl, SbCl₅, isolating the bulb from the vacuum system and shaking the contents of the bulb as they warmed from liquid nitrogen temperature. Color changes indicative of reaction occurred in the solid well below room temperature in the fluoride and chloride systems. For the synthesis of CF3SiF2Cl, the following data correspond to a representative reaction. A 0.93-mmol sample of CF3SiF2I was distilled into a bulb containing 29.6 g (130 mmol) of SbCl3 and 0.97 g (3.2 mmol) of SbCl5. The reaction produced 0.47 mmol of CF3SiF2Cl (51% theoretical yield), with the remainder of the products consisting of approximately equal quantities of CF3SiF3 and (CF3SiF2)2O, along with a much smaller amount of unreacted CF₃SiF₂I. The source of the oxygen is either water in the "anhydrous" SbCl₃ or Sb-O bonds in the solid, or both. Yields for the system where X = Br were somewhat lower than for X = Cl; yields for the production of CF3SiF3 were considerably higher, often surpassing 90%.

Purification of the compounds described in this work was effected by either simple trap-to-trap or low-temperature column distillation. Molecular weights for CF_3SiF_2X , where X = F, Cl, Br, I: calcd, 154.1, 170.5, 215.0, 262.0; found, 154.6; 170.5, 216.5, 260.8.

Reaction of CF3SiF2I with HgO, Sb2O3, and Ag2CO3. Several oxygen-containing compounds were employed in attempts to convert the Si-I function in CF3SiF2I into a siloxane (i.e., CF3SiF2OSiF2CF3). CF3SiF2I reacts rapidly with antimony(III) oxide at or below room temperature, but (CF3SiF2)2O could not be isolated among the products. Instead, SiF4, C2F4, and CF3SiF3 are generated in substantial quantities, along with smaller amounts of SiF₃OSiF₃. Silver carbonate has been utilized in conversion of a P-I bond into a diphosphoxane containing a P-O-P linkage;11 however, interaction of CF3SiF2I with Ag2CO3 led to formation of CF3SiF3 in the presence or absence of added SbCl5.

Mercury(II) oxide did prove to be effective in the generation of the desired siloxane if small amounts of SbCl₅ were present. In a typical run, 2.81 mmol of CF3SiF2I was distilled into a bulb containing 26 g (120 mmol) of HgO and 1.0 g (3.3 mmol) of SbCl₅. The bulb was allowed to warm to room temperature and the bulb contents were shaken for 5 min. The reaction generated 0.53 mmol of CF3SiF2-OSiF2CF3 (38% theoretical yield), with the balance of the products being largely CF3SiF3. Smaller amounts of CF3SiF2Cl (from the apparent activity of SbCl5 as a chlorinating agent) and unreacted starting material were also present. Longer contact times of CF3SiF2I

with the solid resulted in partial conversion of $(CF_3SiF_2)_2O$ to CF_3SiF_3 .

Attempted Reaction of CF₃SiF₂I with Mercury. The interaction of CF₃SiF₂I with mercury was examined in the hope of obtaining a Wurtz-type reduction of the silane to yield CF₃SiF₂SiF₂CF₃. In a sealed tube containing a large droplet of mercury and CF₃SiF₂I at a pressure of 100 Torr, no evidence of reaction was obtained after 20 hr at 25° in the dark. The bulb was continuously shaken during the experiment.

Hydrolytic Reactions. Vapor-phase hydrolytic reactions of the CF_3SiF_2X species were examined in such a way that system composition could be monitored as a function of time by means of infrared spectroscopy. Details for the CF_3SiF_2I -water vapor system are given below.

CF3SiF2I-Water Vapor. The system CF3SiF2I-H2O was studied as follows. Reactants were enclosed in the two compartments of a gas-mixing cell in tandem with a gas infrared cell. Small amounts of water vapor were added sequentially to pure CF3SiF2I and the resultant system monitored via its infrared spectrum. A deficiency of water vapor in the range 10:1 to 2:1 initially yields two products: CF3SiF3 and a smaller amount of a material with a strong, broad absorption at 1180 cm⁻¹, characteristic of an Si-O-Si stretch in a fluorosiloxane.¹² On standing for 60 min, a sample of composition 2.5:1 showed extensive further decomposition of CF₃SiF₂I but no significant increase in the amounts of the two compounds cited above. Silicon tetrafluoride was then present, and a white involatile polymer was apparent on the walls of the apparatus. Creation of heterogeneous conditions by condensing the volatiles in the cold finger of the cell and revaporizing several times facilitated the decomposition. After six such cycles, the above sample (2.5:1 silane to water) contained no detectable starting material. The amounts of CF3SiF3 and SiF4 had increased, but the siloxane had begun to recede. Further degradation of the system by adding more water (to a ratio of 1.9:1) occurred by (1) disappearance of the siloxane, (2) attack of the CF3SiF3 to form its known hydrolysis products CF3H and SiF4, and (3) formation of a new compound with major infrared bands at 1093, 1084, and 635 cm^{-1} .

The latter compound was shown to be difluoroiodomethane via comparison with an authentic sample of CF₂HI prepared from the reaction of CF₂ with HI. The source of the CF₂ in the latter reaction was the pyrolytic decomposition of CF₃SiF₃ at 100°.⁹

Pyrolytic Reactions. Thermal decomposition processes were examined by distilling samples into well-flamed glass ampoules of approximately 50-ml volume. The ampoules were sealed and heated to 100°. Subsequent to heating the vessels were mechanically broken while attached to the vacuum line.

 CF_3SiF_2X , X = F, Cl, Br. Each of these compounds decomposes rather rapidly in the vapor phase at 100° (with half-lives less than 30 min) to a mixture of C_2F_4 , c- C_3F_6 , and SiF_3X . Neither of the mixed halosilanes, SiF_3Cl or SiF_3Br , was observed to react with CF_2 or to undergo reactions involving redistribution of halogens under these conditions.

CF₃SiF₂I. The vapor-phase decomposition of CF₃SiF₂I is considerably more complex than those of the other halodifluoro(trifluoromethyl)silanes. Pyrolysis of a sample at 250 Torr and 100° proceeds with a half-life of starting material of ca. 12 min to give products in all three phases on cooling to room temperature. If the pyrolysis is terminated before destruction of the starting material is complete, the colors of the solid products range from orange to brick red; two liquid products of low volatility but relatively high mobility were ruby red and yellow, respectively. Gaseous products of the pyrolysis were identified by infrared and/or NMR spectra as (in approximate order of decreasing abundance) unreacted CF₃SiF₂I, CF₃SiF₃, Si₂F₆, SiF₃I, and CF₂I₂. At least two further, presently uncharacterized compounds were also present in the volatile fraction. It is noteworthy that little or no tetrafluoroethylene is generated under conditions of incomplete pyrolysis.

Extension of the pyrolysis to conditions of total destruction of CF₃SiF₂I results in considerable deposition of colored solids and the yellow liquid discussed above and a somewhat different spectrum of volatile products as well. Most notably, C_2F_4 and SiF₄—the thermal decomposition products of CF₃SiF₃—are now abundant.

Results and Discussion

The fluoroiodosilane CF_3SiF_2I has been found to be a convenient source of several new species of general formula

Table I. Infrared Spectral Frequencies forHalodifluoro(trifluoromethyl)silanes $CF_3SiF_2X^{\alpha}$

- X = I: 1232 s, 1127 vs, 989 m, 896 s, 742 w, 539 m, 505 m, 403 m
- X = Br: 1234 m, 1128 vs, 997 s, 906 s, 740 w, 558 s, 520 w, 410 m

X = Cl: 1245 m, 1132 vs, 1007 s, 919 s, 748 w, 624 s, 443 m

- $X = OSiF_2CF_3$: 1269 m, 1224 m, 1180 vs, 1129 vs, 1015
- s, 952 m, 903 m, 671 w, 507 m X = F: 1251 w, 1133 vs, 1023 s, 866 m, 730 vw, 520 vw,

495 m, 354 m

^a Frequencies in cm⁻¹. Intensities: s, strong; m, medium; w, weak; v, very.

CF₃SiF₂X. These compounds are air-sensitive gases (for X = F, Cl, or Br) or liquids (X = OCF₂SiF₃), stable at room temperature in the vapor phase¹³ but susceptible to pyrolytic or hydrolytic decomposition. The compounds in this series may be legitimately viewed as derivatives of CF₃SiF₃, the simplest perfluoro(alkylsilane), or of the appropriate SiF₃X species on substitution of a CF₃ group for F. The following sections will describe synthetic routes to, characterization of, and pyrolytic and hydrolytic reaction chemistry of these halodifluoro(trifluoromethyl)silanes.

Synthetic Routes to CF_3SiF_2X . The selective exchange of halo or pseudohalo groups between silicon and silver⁶ or mercury(II)⁷ salts has proved to be a versatile and highly useful synthetic technique. An example of such a reaction is

 $2\text{SiH}_3\text{Br} + \text{Ag}_2\text{O} \rightarrow \text{SiH}_3\text{OSiH}_3 + 2\text{AgBr}$

Such reactions are apparently irreversible, and one may construct "conversion series" of the type $I \rightarrow S \rightarrow Br \rightarrow Cl$, $CN \rightarrow O \rightarrow F$ to indicate the direction of allowed exchange on silicon. The silanes used to establish these series were either simple halosilanes or halotrimethylsilanes. We report here the extension of such exchange reactions to polyhalo (or perhalo if CF₃ is considered to be a pseudohalo function) systems and the utility of antimony(III) halides as halogenating agents.

Antimony(III) fluoride has proved useful as a "soft" fluorinating agent for both metal--14 and nonmetal--halogen¹⁵ bonds. We find that SbX₃ reacts smoothly with CF₃SiF₂I to generate CF₃SiF₂X where X = F, Cl, or Br. As expected from consideration of the appropriate bond and lattice energies, the efficiency of the reactions decreases in the order F > Cl > Br. Although Sb₂O₃ is ineffective in synthesizing the siloxane (CF₃SiF₂I with HgO in the presence of small amounts of antimony(V) chloride.

Both AgCN and Hg(CN)₂ were employed in attempts to synthesize CF₃SiF₂CN. The latter would be a potential source of the elusive molecule SiF₃CN. In neither system was exchange observed. Silver cyanide caused decomposition of CF₃SiF₂I into CF₃SiF₃, C₂F₄, and SiF₄; interaction of the silane with mercury(II) cyanide produced only small amounts of CF₃SiF₃.

Attempts to reduce the Si–I bond in CF₃SiF₂I with mercury at room temperature were unsuccessful.

Spectroscopic Characterizations. In addition to vapor density molecular weights (see Experimental Section) and chemical behavior, the compounds described here were characterized largely on the basis of their infrared and fluorine NMR spectra.

The infrared spectra of species of interest are presented in Table I. The spectra contain the characteristic stretching frequencies of Si–F, Si–Cl, Si–Br, Si–I, and Si–O bonds in the appropriate molecules. The most notable feature in the spectra is the remarkable insensitivity of the asymmetric group stretch of the CF₃ group (near 1130 cm⁻¹) to the nature of the group X on silicon. The higher of the stretching frequencies associated with the SiF₂X group (near 1000 cm⁻¹) decreases Derivatives of Trifluoro(trifluoromethyl)silane

 Table II.
 Fluorine NMR Spectral Parameters for Halodifluoro(trifluoromethyl)silanes

	δ _{CF3} ^a	δ_{SiF_2X}	$ J_{\rm FF} ^b$	$J_{{ m SiF}}^{b,c}$	
CF ₃ SiF ₂ I	69.9	120.1	6.9	342.4	
CF ₃ SiF ₂ Br	68.3	127.8	8.2	321.7	
CF ₃ SiF ₂ Cl	67.9	134.3	8.9	303.7	
CF ₃ SiF ₃	66.3	150.7	11.0	273.2	
$(CF_3SiF_2)_2O$	66.9	148.7	10.9	270.9	

^a Chemical shifts in ppm upfield from CCl₃F. Values for CF₃SiF₂I are for a neat sample referenced to external CCl₃F; values for the other compounds in the table correspond to samples including some CF₃SiF₂I, which was used as an internal reference. ^b In Hz. ^c We assume, following the findings of Johannesen et al.¹⁶ that J_{SiF} is always >0.



Figure 1. Correlation of chemical shifts for fluorines in halotrifluorosilanes with those of silicon-bonded fluorines in halodifluoro(trifluoromethyl)silanes. Values are in ppm upfield from CCl_3F . The value for SiF_3I is an average of the values reported in ref 4 and 8.

smoothly in the order F > O > Cl > Br > I.

The frequency of the Si-O-Si stretch in the siloxane (CF₃SiF₂)₂O is similar to that in (SiF₂Cl)₂O¹² and lower than that in (SiF₃)₂O.¹² The latter finding is rather surprising, since one might expect the ability of the CF₃ group to serve as a strong σ acceptor but weak π donor to enhance the π component of the Si-O bond and hence increase its stretching frequency.

Fluorine NMR spectral parameters are listed in Table II. All spectra are first order due to the large difference in chemical shifts between the C-F and Si-F resonances. If the series of compounds is considered in the order $I \rightarrow Br \rightarrow Cl$ $\rightarrow O$, F, three correlations are evident from the NMR spectra: (a) |JFF| increases; (b) δ_{SiF_2X} increases; (c) J_{SiF} decreases. There are some reversals in order between O and F, but in all instances the differences between parameter values for O and F functions are small.

Correlations between $|J_{FF}|$ and substituent electronegativities in fluoroethanes have been developed^{17,18} but are *opposite* in direction to those reported here. The chemical shift of the CF3 group is relatively insensitive to the nature of X but increases monotonically in the order F < O < Cl < Br < I. The progression to higher field for the fluorines in the SiF₂X function as X changes from I through F is consistent with the trend observed in the analogous SiF₃X species. Figure 1 demonstrates the very nearly linear relationship between δ_{SiF_3X} and $\delta_{CF_3SiF_2X}$ as a function of X. J_{SiF} is quite sensitive to the nature of X and should also prove to be of diagnostic value in systems such as these. Figure 2 is a plot of J_{SiF} in SiF₃X vs. J_{SiF} in the corresponding CF₃SiF₂X. The figure clearly reveals the close correlation between the variation of the directly bonded Si-F coupling with substituent in the two



Figure 2. Correlation of directly bonded Si-F coupling constants for halotrifluorosilanes with those for halodifluoro(trifluoro-methyl)silanes.

systems. The behavior of J_{SiF} as a function of substituents on silicon has been discussed in detail elsewhere.¹⁶

Pyrolytic Decompositions. CF₃SiF₂X, X = F, Cl, Br. The disparity of approximately 20 kcal/mol between the Si-F and C-F bond energies provides the basis for the thermal decomposition of CF₃SiF₃ into CF₂ + SiF₄ under mild conditions ($\leq 100^{\circ}$).⁹ We find that CF₃SiF₂Cl and CF₃SiF₂Br behave similarly; that is, each is thermally decomposed rapidly above 100° to form C₂F₄ and c-C₃F₆ (the products derived from CF₂ in the absence of effective trapping reagents) and SiF₃Cl and SiF₃Br, respectively. Surprisingly little has been reported on the chemistry of these halotrifluorosilanes; we feel that the processes just described represent the most straightforward specific synthetic routes to these species.

CF3SiF2I. The vapor-phase pyrolysis of CF3SiF2I appeared to be an ideal route to the little-known compound SiF₃I--the silicon analog of the enormously useful CF3I. Although SiF3I is generated in the pyrolysis of CF₃SiF₂I, the thermolytic process is substantially more complex than those of the other CF₃SiF₂X species discussed above. Partial or total thermal destruction of the starting material at 100° generates, after cooling to 25°, a multitude of products in vapor, liquid, and solid phases. The more volatile portion of the products includes CF3SiF3, SiF3I, Si2F6, CF2I2, C2F4, and SiF4. Condensed-phase products include several highly colored solids and low-volatility (but highly mobile) liquids. Several new-as yet uncharacterized-species are present as reaction products, and product composition is a function of the extent to which decomposition is carried. This is clearly a system of considerable complexity, and elucidation of the mechanism(s) of decomposition must await further efforts, perhaps involving pyrolysis of CF₃SiF₂I in the condensed phase where continual system monitoring via NMR is possible. Our present assumption is that the decomposition process is being complicated by either homolytic cleavage of the Si-I bond or interaction of CF2 with Si-I bonds (and I2, if present), or both.

Hydrolytic Decomposition. What little is known about the hydrolytic behavior of fluorosilanes results almost exclusively from studies in condensed media.¹⁹ We have discovered that several fluorosilanes are surprisingly resistant to hydrolytic decomposition when exposed to limited amounts of water vapor under homogeneous conditions. Our interest in hydrolytic processes in this work was stimulated by a puzzling observation of CF₃SiF₃ as a persistent side product in reactions of CF₃SiF₂I with various of the solid reagents utilized in the conversion series. The suspicion that small amounts of water retained by the solids might be responsible for the behavior was justified

by the investigation of the reaction of CF₃SiF₂I with water vapor. Mixing of the two vapors was effected in a gas-mixing cell in which one compartment was a gas infrared cell. Infrared spectroscopic monitoring of the system revealed initial formation of CF₃SiF₃ and a compound with a strong absorption at 1180 cm⁻¹, a frequency typical of Si-O-Si stretches in fluorosiloxanes. Although not observable in the infrared spectra, HI is also initially present. Admission of additional water vapor and/or subjection of the reactants to quenchvaporize cycles result in, sequentially, (1) depletion (and finally consumption) of the CF3SiF2I, (2) loss of the siloxane, and (3) appearance of the known hydrolytic products of CF3Si-F₃—CF₃H and SiF₄—and formation of CF₂HI.

The presence of HI in the system strongly suggests hydrolytic attack of the silicon-iodine bond to give a silanol, which rapidly condenses to a siloxane

$$CF_3SiF_2I + H_2O \rightarrow HI + CF_3SiF_2OH$$

$$2CF_3SiF_2OH \rightarrow CF_3SiF_2OSiF_2CF_3 + H_2O$$

The identity of the siloxane was verified by its independent synthesis from the reaction of CF3SiF2I with HgO (see Experimental Section for details). The siloxane itself is attacked by water vapor-somewhat less rapidly than the starting material-to give CF₃SiF₃ and involatile polymeric materials.

An important related experiment is the determination of the source of difluorocarbene responsible for the formation of CF₂HI (HI is one of the few efficient room-temperature traps for CF₂). The facts that CF₂HI is not observed so long as CF₃SiF₂I remains in the system and that SiF₃I is not observed among the products suggest that CF3SiF3 may be the source of the CF2. In a control experiment, CF3SiF3 in the presence of excess HI was exposed to water vapor under conditions similar to those described above for the hydrolysis of CF₃SiF₂I. CF₂HI is indeed formed under these conditions, along with SiF4. Anhydrous HI alone does not affect CF3SiF3.

CF₃SiF₂Cl and CF₃SiF₂Br behave similarly to CF₃SiF₂I on exposure to water vapor. Each suffers hydrolytic attack on the heavier halogen and generates CF3SiF3 through the intermediate siloxane (CF3SiF2)2O. A secondary reaction of CF2 with HBr leads to CF2HBr; however, reaction of CF2 with HCl at 25° is apparently too slow to suppress effectively the dimerization of the carbene to C₂F₄.

In summary, the hydrolytic reactions suggest the rate of attack of water vapor on Si-X bonds follows the order I > Br> Cl, O > F. When only Si-F bonds are present—in CF₃SiF₃—the Si-F bond is apparently not directly attacked.²⁰ Instead, water vapor, perhaps acting through an intermediate acid-base complex, promotes α transfer of fluorine to form SiF₄ (again, perhaps complexed) and CF₂. In the presence of the unusually good halocarbene traps HBr and HI the difluorocarbene can be trapped as CF₂HX.

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Registry No. CF₃SiF₂I, 27668-68-4; CF₃SiF₂Br, 54484-28-5; CF3SiF2C1, 54484-29-6; CF3SiF3, 335-06-8; (CF3SiF2)2O, 54484-30-9; SbCl₃, 10025-91-9; SbCl₅, 7647-18-9; HgO, 21908-53-2.

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Kinetics and Mechanism of Carborane Formation

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The kinetics of 1.2-dicarba-closo-dodecaborane(12) formation from $B_{10}H_{12}[(CH_3)_2S]_2$ and several acetylenes [HC=CCH₂Br, $HC = CCH_2OC(=O)CH_3$, $HC = C(CH_2)_2CH_3$, $HC = C(CH_2)_3CH_3$, $HC = C(CH_2)_3CI$ have been studied. A mechanism is proposed consistent with the data obtained. ΔH^{\dagger} and ΔS^{\dagger} correlate well with the Taft polar substituent constants for the acetylene substituents.

A wide variety of substituted 1,2-dicarba-closo-dodecaborane(12) derivatives have been synthesized and characterized.²⁻⁴ The most common method for their preparation is through the use of diligand derivatives of decaborane, $B_{10}H_{12}L_2$ (L = Lewis base), and acetylenes. Alkyl derivatives are generally prepared in low yields, ca. 30-40%, from the corresponding acetylenes while other derivatives from acetate and halogen-containing acetylenes are prepared in higher yields (ca. 80-90%).

Except for some preliminary work carried out by the authors at the Rohm and Haas Redstone Research Laboratories in the middle and late 1960's, very little attention has been given to the kinetics of carborane formation. Our preliminary studies indicated that the reaction was first order in B10H12L2 and